NSN 5961-01-317-3141

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-317-3141 **Inclosure Material:** Glass **Overall Length:** 0.382 inches **Terminal Length:** 0.250 inches **Overall Height:** 0.085 inches **Overall Width:** 0.269 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-86 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc all transistor and 20.0 collector to emitter voltage, dc all transistor and 6.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2.4 watts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor and 180.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 12 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: